

Magnetic Imaging in the Electron Microscope

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• Electron interactions and the electron microscope

• Imaging methods in the electron microscope (scanning and transmission – SEM, TEM and STEM)

• Implementation of Lorentz microscopy

• Examples of application of (S)TEM

• Developments



Electron interaction with matter



From Williams and Carter – Transmission Electron Microscopy



Electrons in the electron microscope

Accelerating voltage (kV)	Non- relativistic λ (pm)	Relativistic λ (pm)	Mass (× <i>m</i> ₀)	Velocity (×10 ⁸ m/s)
100	3.86	3.70	1.20	1.64
200	2.73	2.51	1.39	2.09
300	2.23	1.97	1.59	2.33
1000	1.22	0.87	2.96	2.82

Non relativistic calculation

$$eV = \frac{p^2}{2m_o} \quad \lambda = \frac{h}{\sqrt{2m_o eV}}$$

 $\begin{aligned} Relativistic \ calculation \\ E^2 &= p^2 c^2 + \left(m_o c^2\right)^2 \quad \lambda = \frac{h}{\sqrt{2m_o eV \left(1 + \frac{eV}{2m_o c^2}\right)}} \end{aligned}$



The Scanning Electron Microscope

Scanning electron microscopy (SEM) is a technique for imaging **surfaces**.

The electrons are emitted from a source called the gun. Usually emits electrons of energy in range 5–40 keV.

Special lenses focus the electrons by using magnetic fields.

Probe size limited by diffraction and aberrations.





SEM Detection



Secondary electrons (SE) have energies up to \sim 50eV.

Backscattered electrons (BSE) have energies up to primary beam energy.

Faraday cage voltage means can predominantly image SE or BSE.



Type I contrast utilises the fact that the secondary electrons are deflected by stray fields from the sample. Orientation of detector can then show contrast from regions with different directions of stray field.







Type II contrast utilises the fact that the backscattered electrons are deflected by the magnetic induction within the sample. This results in an increased or decreased BSE signal.







SEMPA

Scanning electron microscope with polarisation analysis:

- polarisation of secondary electrons are detected
- gives magnetisation of local region







Components of the transmission electron microscope (TEM)

A Cartoon TEM

A real TEM





Transmission Electron Microscopy

Concentrate now on "regular" TEM.

Samples must be thin (\sim 100nm).

Standard TEM has objective lens on.

Magnetic imaging is normally carried out with objective off or weakly excited – Lorentz microscopy.









TEM – beware!



Say what you see?

You are seeing projected information – should verify what you are seeing before making detailed interpretation.



Lorentz microscopy

Lorentz microscopy:

- thin films (< 100nm)
- high spatial resolution (<10 nm has been demonstrated)
- information on domain and domain wall structures
- sensitive to induction (contrast arises from specimen magnetisation and stray fields)
- quantitative information on spatial distribution of integrated induction components
- suitable for real time studies involving field, currents and temperature variation
- availability of complementary (perfectly registered) nanostructural information



Lorentz TEM operation



Also use custom specimen rods to deliver field, heat and current pulses to samples in-situ

Standard mode:

Objective lens generates high (few Tesla) magnetic fields perpendicular to the sample plane

Lorentz:

Switch off objective lens!!!



Field-free/low field mode:

- Instead use Lorentz/mini-lenses
- Perform in-situ magnetising experiments by mild excitation of objective lens and tilting the sample



Lorentz TEM imaging: Fresnel mode





Lorentz STEM imaging: differential phase contrast





 $1000 \times 200 \text{ nm}^2$ permalloy element, 40 nm thick



Lorentz microscopy – Key points

Fresnel imaging

- quick and simple method for getting domain geometry
- generally non-linear imaging
- ideal for overview of magnetisation processes

DPC imaging

- sensitive to induction (contrast arises from specimen magnetisation and stray fields)
- quantitative information on spatial distribution of integrated induction components
- good for detailed induction maps

In both cases have to be aware contrast in images arises also from non-magnetic sources.



Thin films with perpendicular anisotropy in contact with heavy metal – large spin orbit coupling.

Gives rise to Dzyaloshinskii-Moriya interaction at interface.





In absence of DM interaction expect divergence free Bloch walls.

DM interaction should promote Néel walls with defined chirality depending on sign of **D**.



Interfacial exchange – Néel walls

Can we identify

i) if walls are of Néel type?ii) chirality of wall?

Pair of "winding" Néel walls

$$\uparrow / / \rightarrow \land \downarrow / / \rightarrow \land \uparrow$$



Thin films magnetised perpendicular to plane of film. Need to be able to identify Bloch and Néel walls – use Fresnel imaging. Electron beam perpendicular to screen.





Ta(3.2 nm)/Pt(3 nm)/Co(0.8 nm)/AlOx(3 nm) DC sputtering AlOx layer which was deposited by the RF Ar plasma.



Images proves that the walls are Néel. Does not prove same chirality though.



Pushing walls together in field in TEM and MOKE. No DMI – should get easy annihilation DMI – divergent walls will repel each other





A Hrabec et al, Nature Communications, 6 8957 (2015).



Atomic Resolution Microscope



Scanning transmission electron microscope with aberration corrector for probe.

STEM resolution specification:

Standard mode (objective lens on)

<<u>100pm</u>

Lorentz mode (field free)

~<u>1nm</u>



Exchange bias in a multi-layered system

Si / SiO / NiFe(20nm)/[FeMn(15nm)/NiFe(20nm)] X 10/Ta



VSM

Cross-section



Si/SiO/NiFe(20nm)/[FeMn(15nm)/NiFe(20nm)]×10/Ta



McVitie et al, Ultramicroscopy. 152, 57, 2015



Differential Phase Contrast imaging becomes very difficult when dealing with:

• perpendicularly magnetised very thin films (<1 nm thick → very small Lorentz deflection)

• weak moment materials

• strong diffraction contrast from polycrystalline structure

• bend contours in single crystals



Diffraction effects

Differential scattering from randomly oriented grains







Highlighting the problem

Example, 30 nm thick permalloy square (1µm)

Low mag looks OK

Higher mag – diffraction contrast dominating (grains 5–10 nm).

Differently oriented grains:each has different scatteringsimple normalisation does not work





Look at 20nm thick permalloy film (doped with Pt) containing 180° domain wall.

Resolution around 3 nm.

Regular DPC image shown.



Pixelated diffraction pattern from this sample. Use Orius CCD camera. (~12 mins to acquire 100×100 pixel set)







Processing of data

For the diffraction data set use two approaches to filter out high spatial frequency information:

- •Thresholding and centre of mass
- •Edge detection

500 µrad



Threshold



Better





Processing of data

For the diffraction data set use two approaches to filter out high spatial frequency information:

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- •Edge detection



Cross correlation





Better





× 10.43

Domain wall profile, DPC vs Pix DPC



200 nm



Krajnak et al, Ultramicroscopy. 165, 42, 2016

240 260

100 120 140 160 180 200 220

80



•Lorentz TEM allows imaging of domain structures with high resolution

•Simple (non-linear) domain geometry imaging and quantitative induction maps possible

 In-situ experiments allow response to an external field or applied current to be observed

•Often correlate magnetic structure with physical and chemical structure

•Developments in imaging allow weak signals to be measured



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